NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = open

Rev. 08 — 9 February 2006

Product data sheet

1. Product profile

1.1 General description

NPN Resistor-Equipped Transistors (RET) family.

Table 1: Product overview

Type number	Package			PNP complement
	Philips	JEITA	JEDEC	_
PDTC114TE	SOT416	SC-75	-	PDTA114TE
PDTC114TK	SOT346	SC-59A	TO-236	PDTA114TK
PDTC114TM	SOT883	SC-101	-	PDTA114TM
PDTC114TS ^[1]	SOT54	SC-43A	TO-92	PDTA114TS
PDTC114TT	SOT23	-	TO-236AB	PDTA114TT
PDTC114TU	SOT323	SC-70	-	PDTA114TU

[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 100 mA output current capability

1.3 Applications

- Digital applications
- Controlling IC inputs

1.4 Quick reference data

- Reduces component count
- Reduces pick and place costs
- Cost-saving alternative for BC847 series in digital applications
- Switching loads

Table 2: **Quick reference data** Symbol Conditions Min Max Unit Parameter Тур open base 50 V VCEO collector-emitter voltage -output current 100 mΑ I_{O} --R1 bias resistor 1 (input) 7 10 13 kΩ



NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = open

2. Pinning information

Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		
3	GND (emitter)		1 R1 3 006aaa218
SOT54A			
1	input (base)		
2	output (collector)		2
3	GND (emitter)	1 2 001aab348	1 R1 006aaa218
SOT54 va	riant		
1	input (base)		
2	output (collector)	The second secon	
3	GND (emitter)	U U U U U U U U U U U U U U U U U U U	1 R1 006aaa218
SOT23; S	OT323; SOT346; SOT416		
1	input (base)		
2	GND (emitter)	3	3
3	output (collector)	2	1 2 sym012
SOT883			
1	input (base)		· · · · · · · · · · · · · · · · · · ·
2	GND (emitter)		
3	output (collector)	2 Transparent top view	1 2 sym012

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Product data sheet

NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = open

3. Ordering information

Table 4: Ordering information							
Type number	Package	Package					
	Name	Description	Version				
PDTC114TE	SC-75	plastic surface mounted package; 3 leads	SOT416				
PDTC114TK	SC-59A	plastic surface mounted package; 3 leads	SOT346				
PDTC114TM	SC-101	leadless ultra small plastic package; 3 solder lands; body $1.0\times0.6\times0.5$ mm	SOT883				
PDTC114TS	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54				
PDTC114TT	-	plastic surface mounted package; 3 leads	SOT23				
PDTC114TU	SC-70	plastic surface mounted package; 3 leads	SOT323				

[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

4. Marking

Table 5: Marking codes	
Type number	Marking code [1]
PDTC114TE	24
PDTC114TK	24
PDTC114TM	DT
PDTC114TS	TC114T
PDTC114TT	*12
PDTC114TU	*24

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

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5. Limiting values

Table 6: In accordai	Limiting values nce with the Absolute Maximu	um Rating System	(IEC 601	34).		
Symbol	Parameter	Conditions	N	lin	Мах	Unit
V _{CBO}	collector-base voltage	open emitter	-		50	V
V _{CEO}	collector-emitter voltage	open base	-		50	V
V _{EBO}	emitter-base voltage	open collector	-		5	V
lo	output current		-		100	mA
I _{CM}	peak collector current	single pulse; $t_p \leq 1 \text{ ms}$	-		100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$				
	SOT416		<u>[1]</u> _		150	mW
	SOT346		<u>[1]</u> _		250	mW
	SOT883		[2] [3] _		250	mW
	SOT54		<u>[1]</u> _		500	mW
	SOT23		<u>[1]</u> _		250	mW
	SOT323		<u>[1]</u> _		200	mW
T _{stg}	storage temperature		_	65	+150	°C
Tj	junction temperature		-		150	°C
T _{amb}	ambient temperature		_	65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 60 µm copper strip line, standard footprint.

6. Thermal characteristics

Table 7:	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> -	-	833	K/W
	SOT346		<u>[1]</u> _	-	500	K/W
	SOT883		[2] [3] _	-	500	K/W
	SOT54		<u>[1]</u> -	-	250	K/W
	SOT23		<u>[1]</u> -	-	500	K/W
	SOT323		<u>[1]</u> _	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

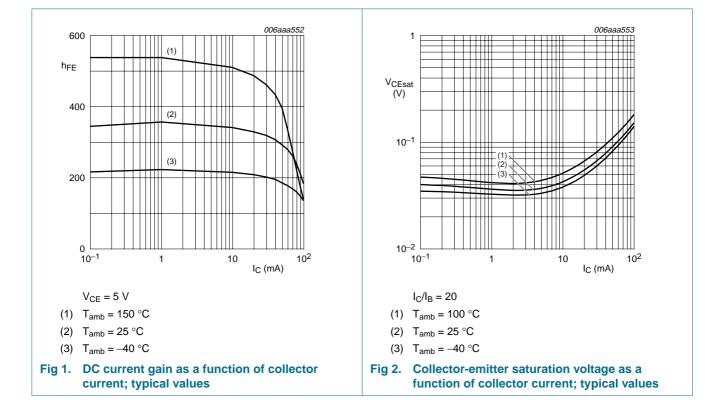
[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 60 μ m copper strip line, standard footprint.

NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = open

7. Characteristics

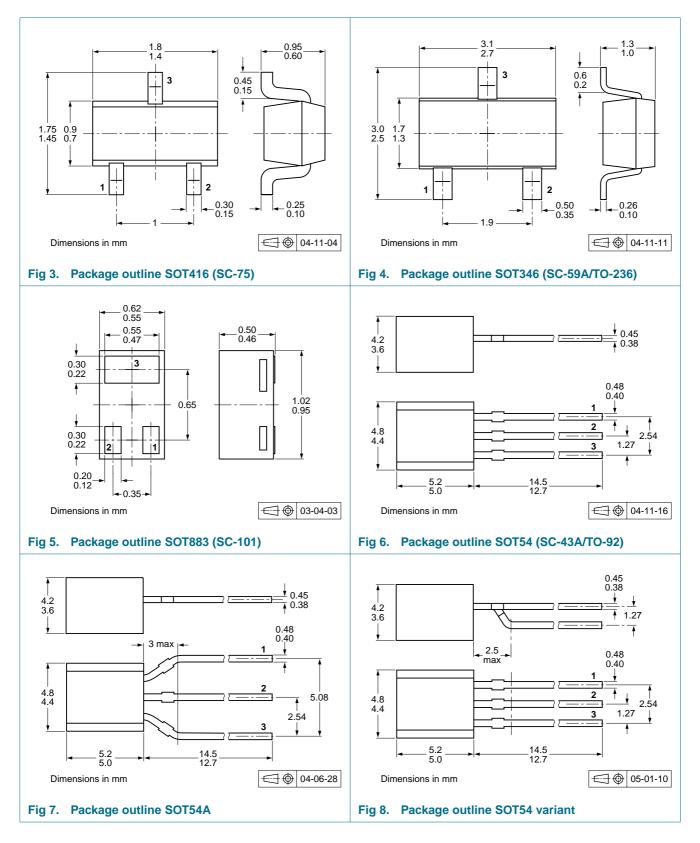
Table 8: $T_{amb} = 25$	Characteristics	ecified.				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	-	-	100	nA
I _{CEO}	collector-emitter	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	1	μA
cut-off current		$\label{eq:VCE} \begin{array}{l} V_{CE} = 30 \; V; \; I_{B} = 0 \; A; \\ T_{j} = 150 \; ^{\circ}C \end{array}$	-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	100	nA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 1 \text{ mA}$	200	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_{C} = 10 mA; I_{B} = 0.5 mA	-	-	150	mV
R1	bias resistor 1 (input)		7	10	13	kΩ
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A};$ f = 1 MHz	-	-	2.5	pF



Table

NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = open

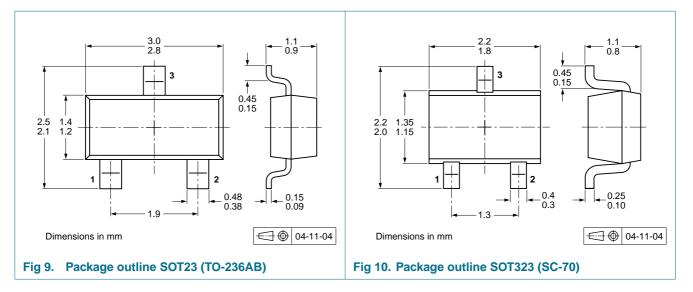
8. Package outline



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9. Packing information

Table 9: Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packin	Packing quantity		
			3000	5000	10000	
PDTC114TE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTC114TK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTC114TM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTC114TS	SOT54	bulk, straight leads	-	-412	-	
	SOT54A	tape and reel, wide pitch	-	-	-116	
		tape ammopack, wide pitch	-	-	-126	
	SOT54 variant	bulk, delta pinning	-	-112	-	
PDTC114TT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
PDTC114TU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	

[1] For further information and the availability of packing methods, see Section 15.

NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = open

10. Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
PDTC114T_SER_8	20060209	Product data sheet	-	-	PDTC114T_SER_7
Modifications:	information	of this data sheet has standard of Philips S er PDTC114TEF remo	emiconductors.	to comply with the	e new presentation and
		oduct overview": EIAJ		mended to JEITA	
		2 "Features": amended 3 "Applications": amen			
		, 7 and 8: added			
	 Section 9 " 	, <u>5</u> , <u>6</u> , <u>9</u> and <u>10</u> : super Packing information": "Trademarks": added		ed package outline	e drawings
PDTC114T_SER_7	20041011	Product	-	9397 750 14186	PDTC114T_SERIES @
	20041011	specification		3337 730 14100	
PDTC114T_SERIES_6	20040817	Product specification	-	9397 750 13664	PDTC114T_SERIES_5
PDTC114T_SERIES_5	20040119	Product specification	-	9397 750 11731	PDTC114T_SERIES_4
PDTC114T_SERIES_4	20030414	Product specification	-	9397 750 11011	PDTC114TE_2 PDTC114TK_2 PDTC114TS_2 PDTC114TT_3 PDTC114TU_3
PDTC114TU_3	19990416	Preliminary specification	-	9397 750 05599	PDTC114TU_2
PDTC114TU_2	19980519	Preliminary specification	-	9397 750 03908	PDTC114TU_1
PDTC114TU_1	19970716	Preliminary specification	-	9397 750 01149	-
PDTC114TT_3	19990416	Objective specification	-	9397 750 05598	PDTC114TT_2
PDTC114TT_2	19980519	Objective specification	-	9397 750 03912	PDTC114TT_1
PDTC114TT_1	19970714	Objective specification	-	9397 750 01371	-
PDTC114TS_2	19980518	Product specification	-	9397 750 03891	PDTC114TS_1
PDTC114TS_1	19970703	Product specification	-	9397 750 02297	-
PDTC114TK_2	19980519	Product specification	-	9397 750 03899	PDTC114TK_1

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	istorycommucu				
Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
PDTC114TK_1	19970528	Product specification	-	9397 750 01367	-
PDTC114TE_2	19980803	Product specification	-	9397 750 04123	PDTC114TE_1
PDTC114TE_1	19970711	Product specification	-	9397 750 02628	-

Table 10: Revision history ...continued

11. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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